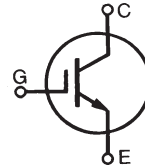


**1200V XPT™ IGBT  
GenX3™**
**IXYK120N120B3  
IXYX120N120B3**

 High-Speed IGBT  
for 10-30 kHz Switching


$$V_{CES} = 1200V$$

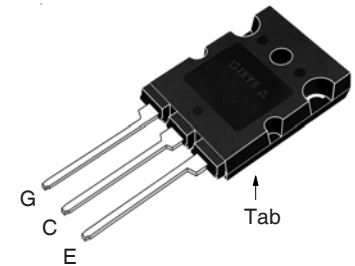
$$I_{C110} = 120A$$

$$V_{CE(sat)} \leq 2.2V$$

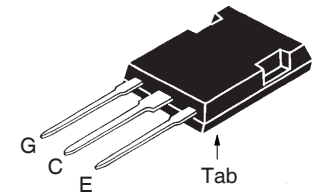
$$t_{fi(typ)} = 260ns$$

Symbol	Test Conditions	Maximum Ratings	
$V_{CES}$	$T_J = 25^\circ C$ to $175^\circ C$	1200	V
$V_{CGR}$	$T_J = 25^\circ C$ to $175^\circ C$ , $R_{GE} = 1M\Omega$	1200	V
$V_{GES}$	Continuous	$\pm 20$	V
$V_{GEM}$	Transient	$\pm 30$	V
$I_{C25}$	$T_C = 25^\circ C$ (Chip Capability)	320	A
$I_{LRMS}$	Terminal Current Limit	160	A
$I_{C110}$	$T_C = 110^\circ C$	120	A
$I_{CM}$	$T_C = 25^\circ C$ , 1ms	800	A
$I_A$	$T_C = 25^\circ C$	60	A
$E_{AS}$	$T_C = 25^\circ C$	2	J
<b>SSOA (RBSOA)</b>	$V_{GE} = 15V$ , $T_{VJ} = 150^\circ C$ , $R_G = 1\Omega$ Clamped Inductive Load	$I_{CM} = 240$ $V_{CE} \leq V_{CES}$	A
$P_C$	$T_C = 25^\circ C$	1500	W
$T_J$		-55 ... +175	$^\circ C$
$T_{JM}$		175	$^\circ C$
$T_{stg}$		-55 ... +175	$^\circ C$
$T_L$	Maximum Lead Temperature for Soldering	300	$^\circ C$
$T_{SOLD}$	1.6 mm (0.062in.) from Case for 10s	260	$^\circ C$
$M_d$	Mounting Torque (TO-264)	1.13/10	Nm/lb.in
$F_c$	Mounting Force (PLUS247)	20..120 / 4.5..27	N/lb
<b>Weight</b>	TO-264P	10	g
	PLUS247	6	g

TO-264P (IXYK)



PLUS247 (IXYX)



G = Gate                      E = Emitter  
C = Collector                Tab = Collector

**Features**

- Square RBSOA
- International Standard Packages
- Positive Thermal Coefficient of  $V_{ce(sat)}$
- Avalanche Rated
- High Current Handling Capability

**Advantages**

- High Power Density
- Low Gate Drive Requirement

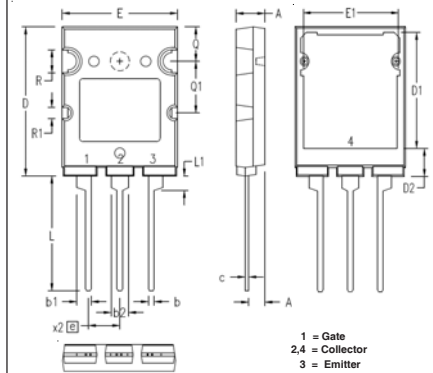
**Applications**

- High Frequency Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts

Symbol	Test Conditions ( $T_J = 25^\circ C$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$BV_{CES}$	$I_C = 250\mu A$ , $V_{GE} = 0V$	1200		V
$V_{GE(th)}$	$I_C = 1mA$ , $V_{CE} = V_{GE}$	3.0		V
$I_{CES}$	$V_{CE} = V_{CES}$ , $V_{GE} = 0V$ $T_J = 150^\circ C$			25 $\mu A$ 1.5 mA
$I_{GES}$	$V_{CE} = 0V$ , $V_{GE} = \pm 20V$			$\pm 200$ nA
$V_{CE(sat)}$	$I_C = 100A$ , $V_{GE} = 15V$ , Note 1 $T_J = 150^\circ C$		1.8 2.4	V V

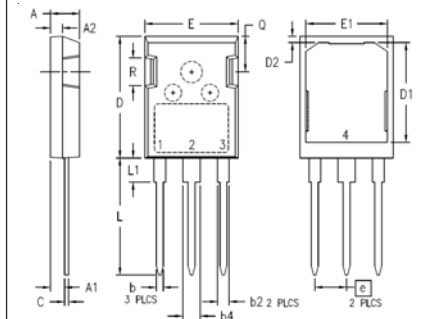
Symbol Test Conditions ( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)		Characteristic Values		
		Min.	Typ.	Max.
$g_{fs}$	$I_C = 60\text{A}, V_{CE} = 10\text{V}, \text{Note 1}$	40	70	S
$C_{ies}$	$V_{CE} = 25\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$		9800	pF
$C_{oes}$			567	pF
$C_{res}$			215	pF
$Q_{g(on)}$	$I_C = I_{C110}, V_{GE} = 15\text{V}, V_{CE} = 0.5 \cdot V_{CES}$		400	nC
$Q_{ge}$			70	nC
$Q_{gc}$			190	nC
$t_{d(on)}$	<b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b> $I_C = 100\text{A}, V_{GE} = 15\text{V}$ $V_{CE} = 0.8 \cdot V_{CES}, R_G = 1\Omega$ Note 2		30	ns
$t_{ri}$			54	ns
$E_{on}$			9.7	mJ
$t_{d(off)}$			340	ns
$t_{fi}$			260	ns
$E_{off}$			21.5	mJ
$t_{d(on)}$	<b>Inductive load, <math>T_J = 150^\circ\text{C}</math></b> $I_C = 100\text{A}, V_{GE} = 15\text{V}$ $V_{CE} = 0.8 \cdot V_{CES}, R_G = 1\Omega$ Note 2		29	ns
$t_{ri}$			55	ns
$E_{on}$			14.7	mJ
$t_{d(off)}$			420	ns
$t_{fi}$			406	ns
$E_{off}$			27.9	mJ
$R_{thJC}$			0.10	$^\circ\text{C/W}$
$R_{thCS}$		0.15		$^\circ\text{C/W}$

**TO-264P Outline**



SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.185	.209	4.70	5.30
A1	.102	.118	2.60	3.00
b	.035	.049	0.90	1.25
b1	.091	.106	2.30	2.70
b2	.110	.126	2.80	3.20
c	.020	.033	0.50	0.85
D	1.012	1.035	25.70	26.30
D1	.783	.799	19.90	20.30
D2	.185	.205	4.70	5.20
E	.776	.799	19.70	20.30
E1	.661	.677	16.80	17.20
e	.215	BSC	5.46	BSC
L	.768	.807	19.50	20.50
L1	.091	.106	2.30	2.70
Q	.228	.244	5.80	6.20
Q1	.346	.362	8.80	9.20
$\phi R$	.150	.165	3.80	4.20
$\phi R1$	.071	.087	1.80	2.20

**PLUS247™ Outline**



Terminals: 1 - Gate  
2,4 - Collector  
3 - Emitter

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b1	.075	.087	1.91	2.20
b4	.115	.126	2.92	3.20
C	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.690	16.51	17.53
D2	.035	.050	0.89	1.27
E	.620	.635	15.75	16.13
E1	.520	.560	13.08	14.22
e	.215	BSC	5.45	BSC
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83

Notes:

1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .
2. Switching times & energy losses may increase for higher  $V_{CE}$  (clamp),  $T_J$  or  $R_G$ .

**ADVANCE TECHNICAL INFORMATION**

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:	4,835,592	4,931,844	5,049,961	5,237,481	6,162,665	6,404,065 B1	6,683,344	6,727,585	7,005,734 B2	7,157,338B2
	4,860,072	5,017,508	5,063,307	5,381,025	6,259,123 B1	6,534,343	6,710,405 B2	6,759,692	7,063,975 B2	
	4,881,106	5,034,796	5,187,117	5,486,715	6,306,728 B1	6,583,505	6,710,463	6,771,478 B2	7,071,537	



---

Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [IGBT Transistors](#) category:*

*Click to view products by [IXYS](#) manufacturer:*

Other Similar products are found below :

[748152A](#) [FGH60T65SHD\\_F155](#) [APT100GT60B2RG](#) [APT13GP120BG](#) [APT20GN60BG](#) [APT20GT60BRDQ1G](#) [APT25GN120B2DQ2G](#)  
[APT35GA90BD15](#) [APT36GA60BD15](#) [APT40GP60B2DQ2G](#) [APT40GP90B2DQ2G](#) [APT50GN120B2G](#) [APT50GT60BRG](#)  
[APT64GA90B2D30](#) [APT70GR120J](#) [NGTB10N60FG](#) [NGTB30N60L2WG](#) [NGTG25N120FL2WG](#) [IGP30N60H3XKSA1](#) [STGB15H60DF](#)  
[STGFW20V60DF](#) [STGFW30V60DF](#) [STGFW40V60F](#) [STGWA25H120DF2](#) [FGB3236\\_F085](#) [APT25GN120BG](#) [APT25GR120S](#)  
[APT30GN60BDQ2G](#) [APT30GN60BG](#) [APT30GP60BG](#) [APT30GS60BRDQ2G](#) [APT30N60BC6](#) [APT35GP120JDQ2](#) [APT36GA60B](#)  
[APT45GR65B2DU30](#) [APT50GP60B2DQ2G](#) [APT68GA60B](#) [APT70GR65B](#) [APT70GR65B2SCD30](#) [GT50JR22\(STA1ES\)](#) [TIG058E8-TL-H](#)  
[IDW40E65D2](#) [NGTB50N60L2WG](#) [STGB10H60DF](#) [STGB20V60F](#) [STGB40V60F](#) [STGFW80V60F](#) [IGW40N120H3FKSA1](#)  
[RJH60D7BDPQ-E0#T2](#) [APT40GR120B](#)